Quad Complementary CMOS Analog Switch

DESCRIPTION

The versatile DG213 analog switch has two NC and two NO switches. It can be used in various configurations, including four single-pole single-throw (SPST), two single-pole double-throw (SPDT), one “T” switch, one DPDT, etc. This device is fabricated in a Vishay Siliconix’ proprietary high-voltage silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

This analog switch was designed for a wide variety of general purpose applications in telecommunications, instrumentation, process control, computer peripherals, etc. An improved charge injection compensation design minimizes switching transients. These switches can handle up to ± 22 V, and have an improved continuous current rating of 30 mA. An epitaxial layer prevents latchup.

All switches feature true bi-directional performance in the on condition, and will block signals to the supply levels in the off condition.

For additional information, please refer to Application Note AN208 (FaxBack document #70606).

FEATURES

- ± 22 V supply voltage rating
- TTL and CMOS compatible logic
- Low on-resistance - $r_{DS(on)}$: 45 Ω
- Low leakage - $I_{D(on)}$: 20 pA
- Single supply operation possible
- Extended temperature range
- Fast switching - t_{ON}: 85 ns

Pb-free Available

RoHS* COMPLIANT

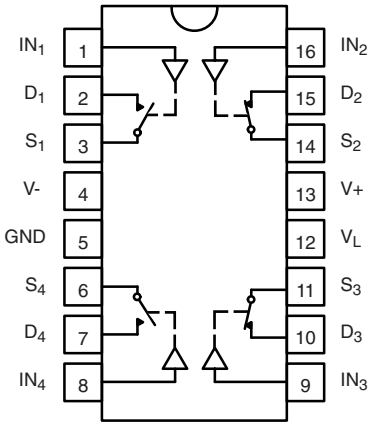
BENEFITS

- Low charge injection - Q: 1 pC
- Wide analog signal range
- Simple logic interface
- Higher accuracy
- Minimum transients
- Reduced power consumption
- Low cost

APPLICATIONS

- Industrial instrumentation
- Test equipment
- Communications systems
- Computer peripherals
- Portable instruments
- Sample-and-hold circuits

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Top View

TRUTH TABLE		
Logic	SW_1, SW_4	SW_2, SW_3
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply.

ORDERING INFORMATION			
Temp. Range	**Package**	**Standard Part Number**	**Lead (Pb)-free Part Number**
- 40 °C to 85 °C	16-Pin Plastic DIP	DG213DJ	DG213DJ-E3
	16-Pin Narrow SOIC	DG213DY DG213DY-T1	DG213DY-E3 DG213DY-T1-E3
	16-Pin TSSOP	DG213DQ DG213DQ-T1	DG213DQ-E3 DG213DQ-T1-E3

ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted			
Parameter		**Limit**	**Unit**
Voltages Referenced V+ to V-		44	V
GND		25	
Digital Inputs[a] V_S, V_D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current, Any Terminal		30	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature		- 65 to 125	°C
Power Dissipation[b]	16-Pin Plastic DIP[c]	470	mW
	16-Pin Narrow SOIC[d]	640	
	16-Pin TSSOP[d]	500	

Notes:
a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 6.5 mW/°C above 75 °C.
d. Derate 7.6 mW/°C above 75 °C.

SPECIFICATIONS

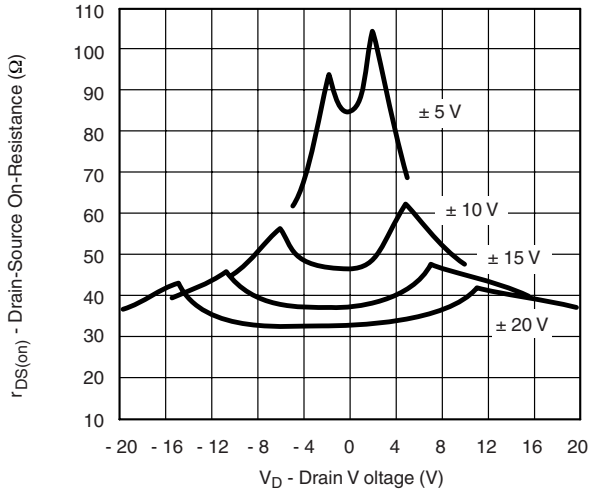
Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V, V_L = 5 V, V_{IN} = 2.4 V, 0.8 V[e]	Temp.[a]	D Suffix - 40 °C to 85 °C Min.[c]	Typ.[b]	Max.[c]	Unit
Analog Switch							
Analog Signal Range[d]	V_{ANALOG}		Full	V-		V+	V
Drain-Source On-Resistance	$r_{DS(on)}$	V_D = ± 10 V, I_S = 1 mA	Room Full		45	60 85	Ω
$r_{DS(on)}$ Match	$\Delta r_{DS(on)}$		Room		1	2	
Source Off Leakage Current	$I_{S(off)}$	V_S = ± 14 V, V_D = ± 14 V	Room Full	- 0.5 - 5	± 0.01	0.5 5	nA
Drain Off Leakage Current	$I_{D(off)}$	V_D = ± 14 V, V_S = ± 14 V	Room Full	- 0.5 - 5	± 0.01	0.5 5	
Drain On Leakage Current[f]	$I_{D(on)}$	V_S = V_D = 14 V	Room Full	- 0.5 - 10	± 0.02	0.5 10	
Digital Control							
Input Voltage High	V_{INH}		Full	2.4			V
Input Voltage Low	V_{INL}		Full			0.8	
Input Current	I_{INL} or I_{INH}	V_{INH} or V_{INL}	Full	- 1		1	µA
Input Capacitance	C_{IN}		Room		5		pF
Dynamic Characteristics							
Turn-On Time	t_{ON}	V_S = 10 V See Figure 2	Room		85	130	ns
Turn-Off Time	t_{OFF}		Room		55	100	
Break-Before-Make Time Delay	t_D	V_S = 10 V, See Figure 3	Room	15	25		
Charge Injection	Q	C_L = 1000 pF, V_g = 0 V, R_g = 0 Ω	Room		1		pC
Source-Off Capacitance	$C_{S(off)}$	V_S = 0 V, f = 1 MHz	Room		5		pF
Drain-Off Capacitance	$C_{D(off)}$		Room		5		
Channel On Capacitance	$C_{D(on)}$	V_D = V_S = 0 V, f = 1 MHz	Room		16		
Off-Isolation	OIRR	C_L = 15 pF, R_L = 50 Ω V_S = 1 V_{RMS}, f = 100 kHz	Room		90		dB
Channel-to-Channel Crosstalk	X_{TALK}		Room		95		
Power Supply							
Positive Supply Current	I+	V_{IN} = 0 or 5 V	Room Full			1 5	µA
Negative Supply Current	I-		Room Full	- 1 - 5			
Logic Supply Current	I_L		Room Full			1 5	
Power Supply Range for Continuous Operation	V_{OP}		Full	± 3		± 22	V

SPECIFICATIONS for Unipolar Supply							
Parameter	**Symbol**	**Test Conditions Unless Otherwise Specified** V+ = 12 V, V- = 0 V, V_L = 5 V, V_{IN} = 2.4 V, 0.8 V[e]	**Temp.[a]**	**D Suffix** - 40 °C to 85 °C **Min.[c]**	**Typ.[b]**	**Max.[c]**	**Unit**
Analog Switch							
Analog Signal Range[d]	V_{ANALOG}		Full	V-		V+	V
Drain-Source On-Resistance	$r_{DS(on)}$	V_D = 3 V, I_S = 1 mA	Room Full		90	110 140	Ω
Dynamic Characteristics							
Turn-On Time	t_{ON}	See Figure 2	Room		125	200	ns
Turn-Off Time	t_{OFF}		Room		45	100	
Break-Before-Make Time Delay	t_D	V_S = 8 V, See Figure 3	Room	50	80		
Charge Injection	Q	C_L = 1 nF, V_{gen} = 6 V, R_{gen} = 0 Ω	Room		4		pC
Power Supply							
Positive Supply Current	I+	V_{IN} = 0 or 5 V	Room Full			1 5	µA
Negative Supply Current	I-		Room Full	- 1 - 5			
Logic Supply Current	I_L		Room Full			1 5	
Power Supply Range for Continuous Operation	V_{OP}		Full	+ 3		+ 40	V

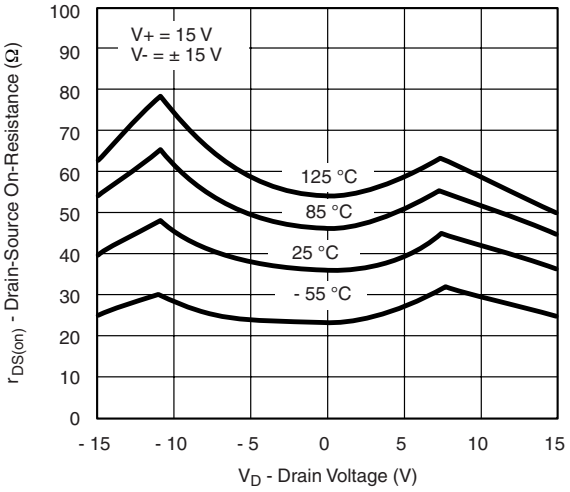
Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

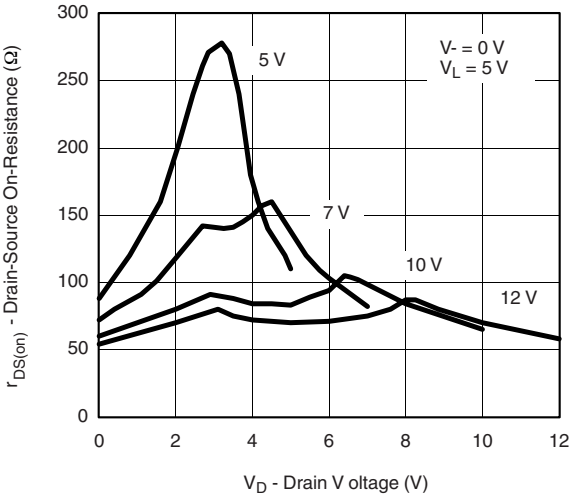
TYPICAL CHARACTERISTICS T_A = 25 °C, unless otherwise noted



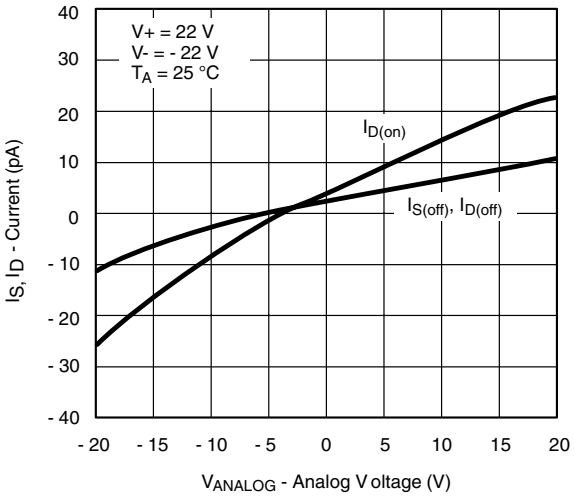
$r_{DS(on)}$ vs. V_D and Power Supply Voltages



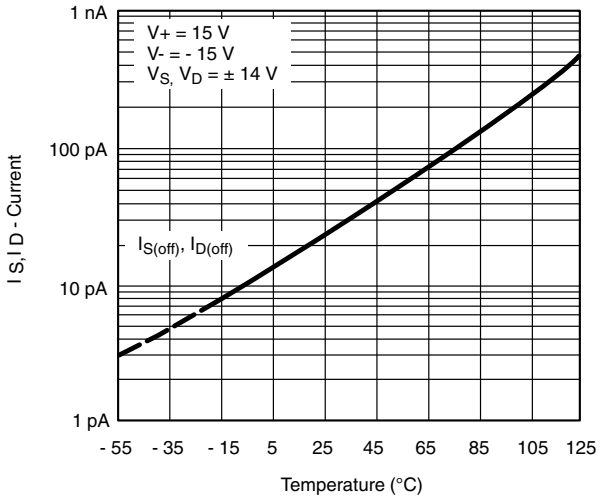
$r_{DS(on)}$ vs. V_D and Temperature



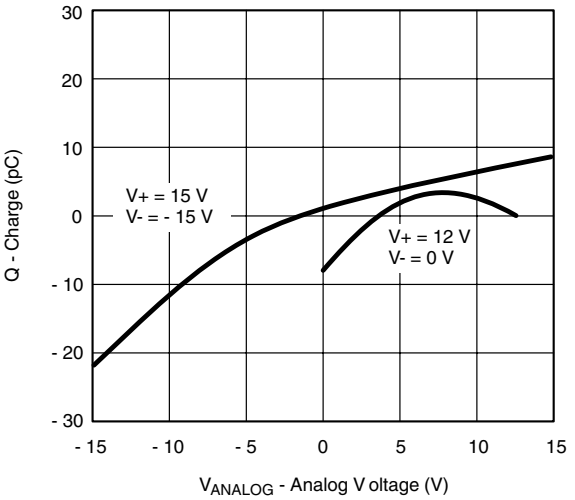
$r_{DS(on)}$ vs. V_D and Single Power Supply Voltages



Leakage Currents vs. Analog Voltage

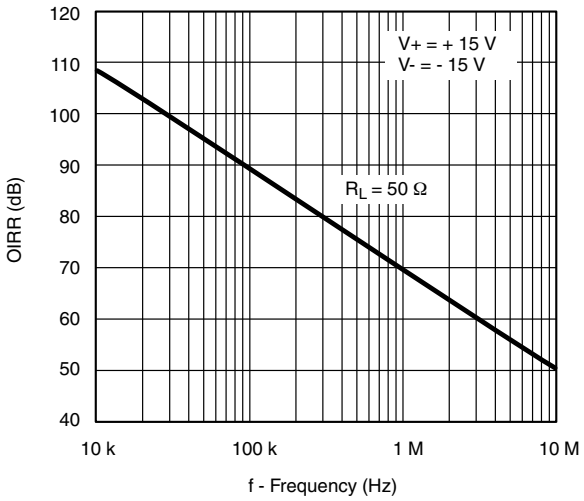


Leakage Current vs. Temperature



Q_S, Q_D - Charge Injection vs. Analog Voltage

TYPICAL CHARACTERISTICS T_A = 25 °C, unless otherwise noted



Off Isolation vs. Frequency

SCHEMATIC DIAGRAM Typical Channel

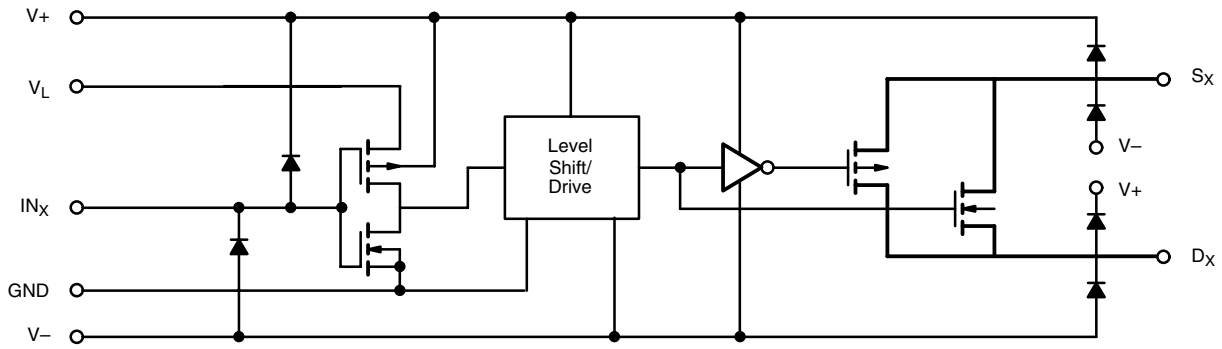
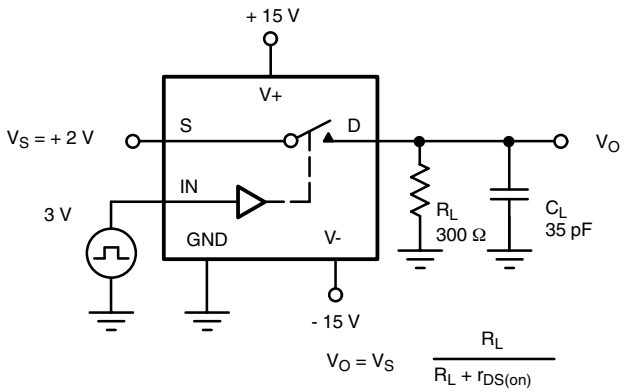


Figure 1.

TEST CIRCUITS



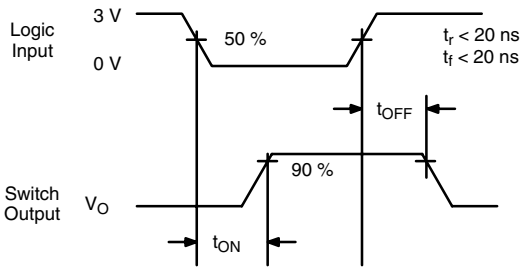
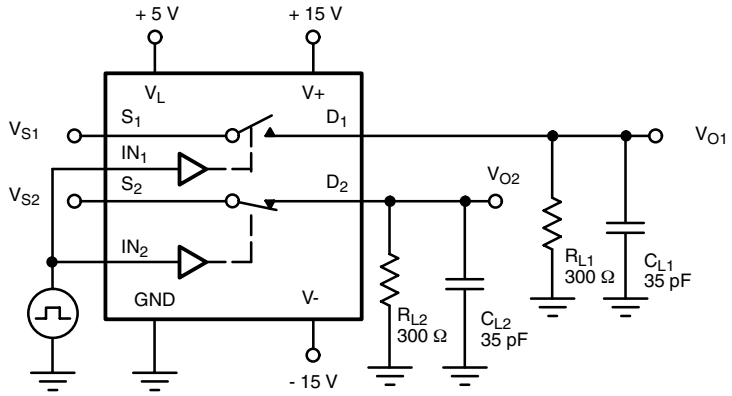


Figure 2. Switching Time

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

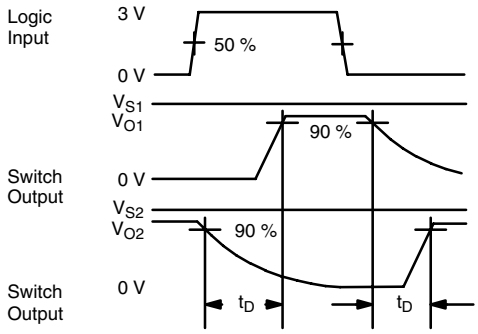


Figure 3. Break-Before-Make

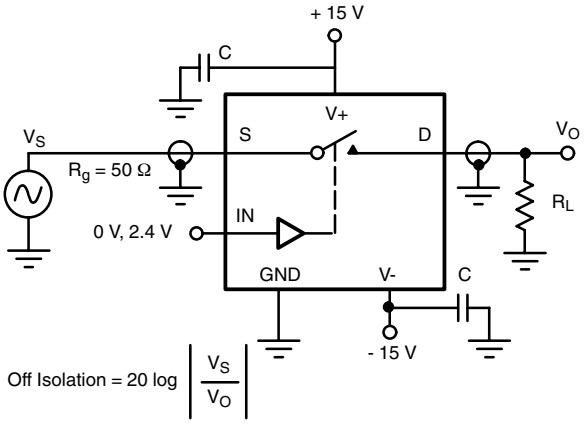


Figure 4. Off Isolation

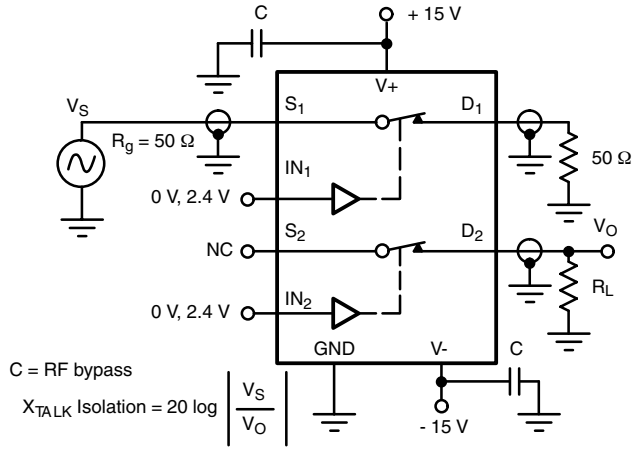
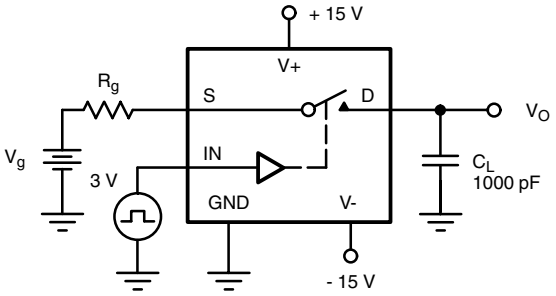
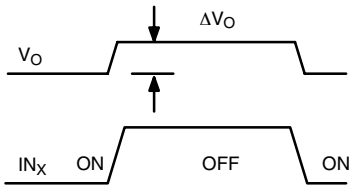


Figure 5. Channel-to-Channel Crosstalk





ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$

Figure 6. Charge Injection

APPLICATIONS

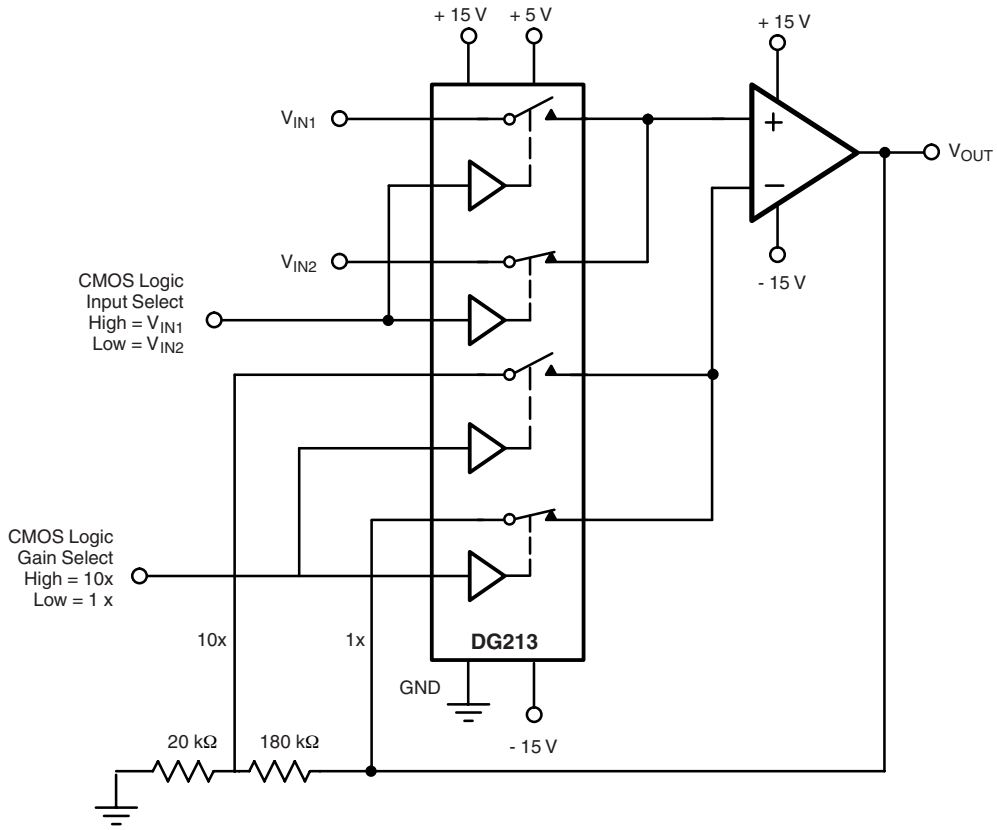
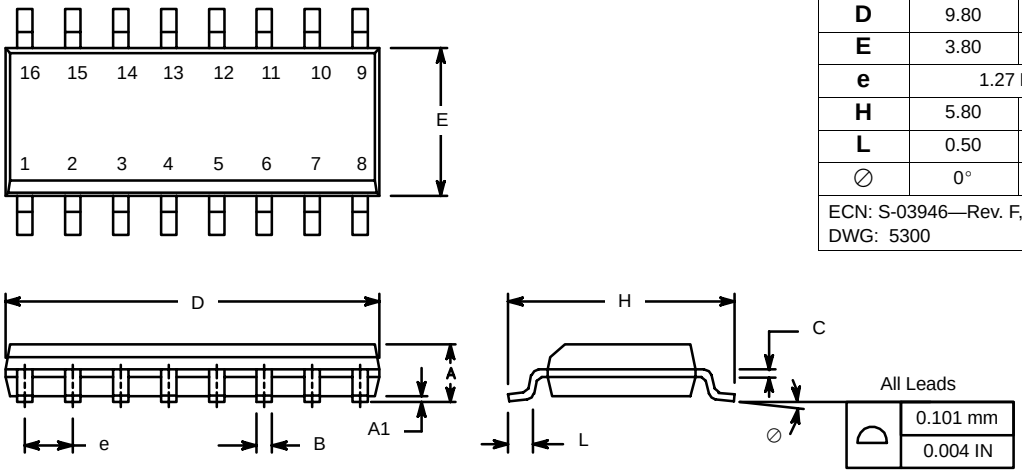


Figure 7. Low Power Non-Inverting Amplifier with Digitally Selectable Inputs and Gain

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?70662.

SOIC (NARROW): 16-LEAD

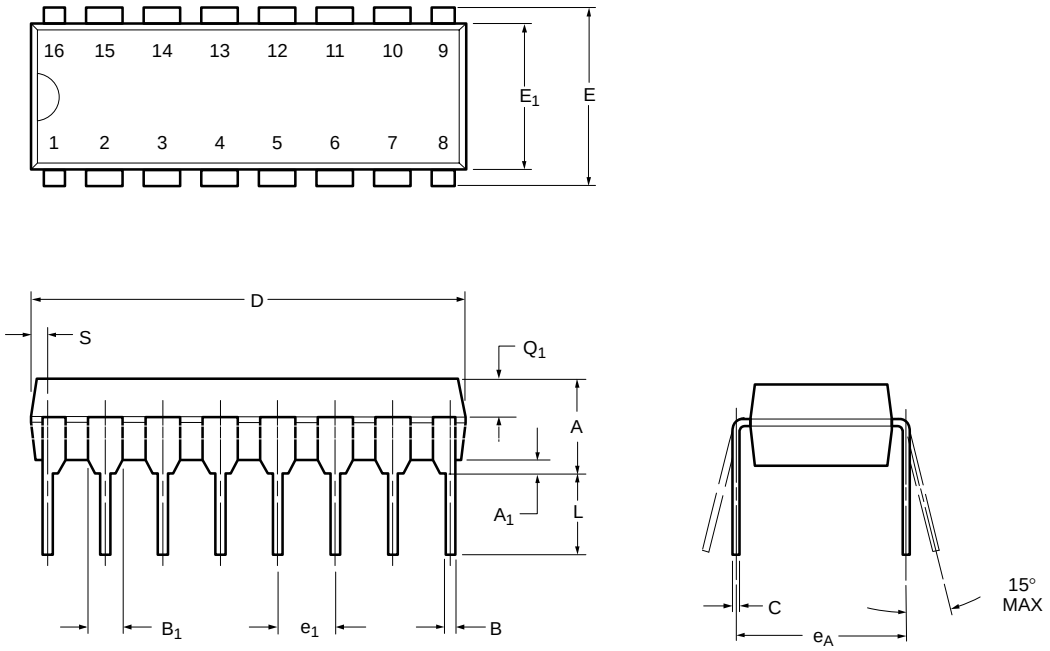
JEDEC Part Number: MS-012



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A_1	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
⊘	0°	8°	0°	8°

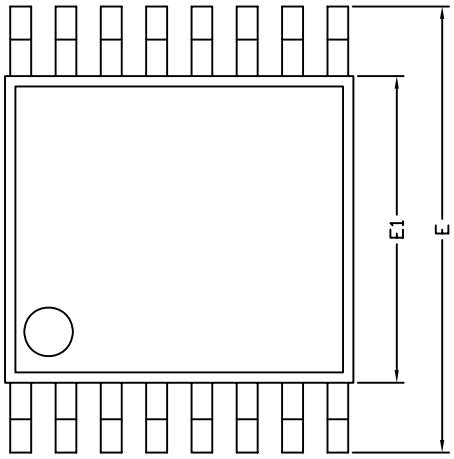
ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300

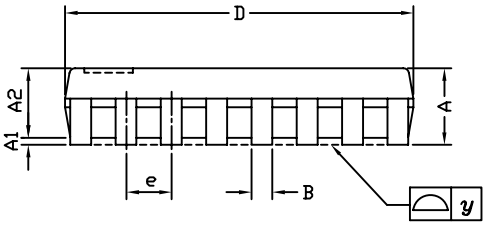
PDIP: 16-LEAD

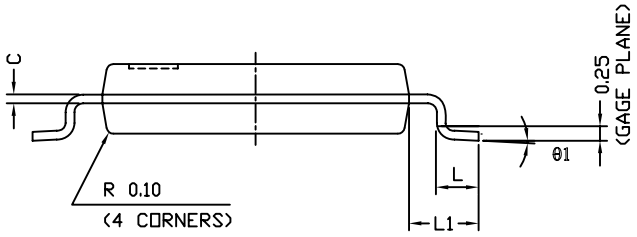


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A_1	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B_1	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E_1	5.59	7.11	0.220	0.280
e_1	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q_1	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482				

TSSOP: 16-LEAD

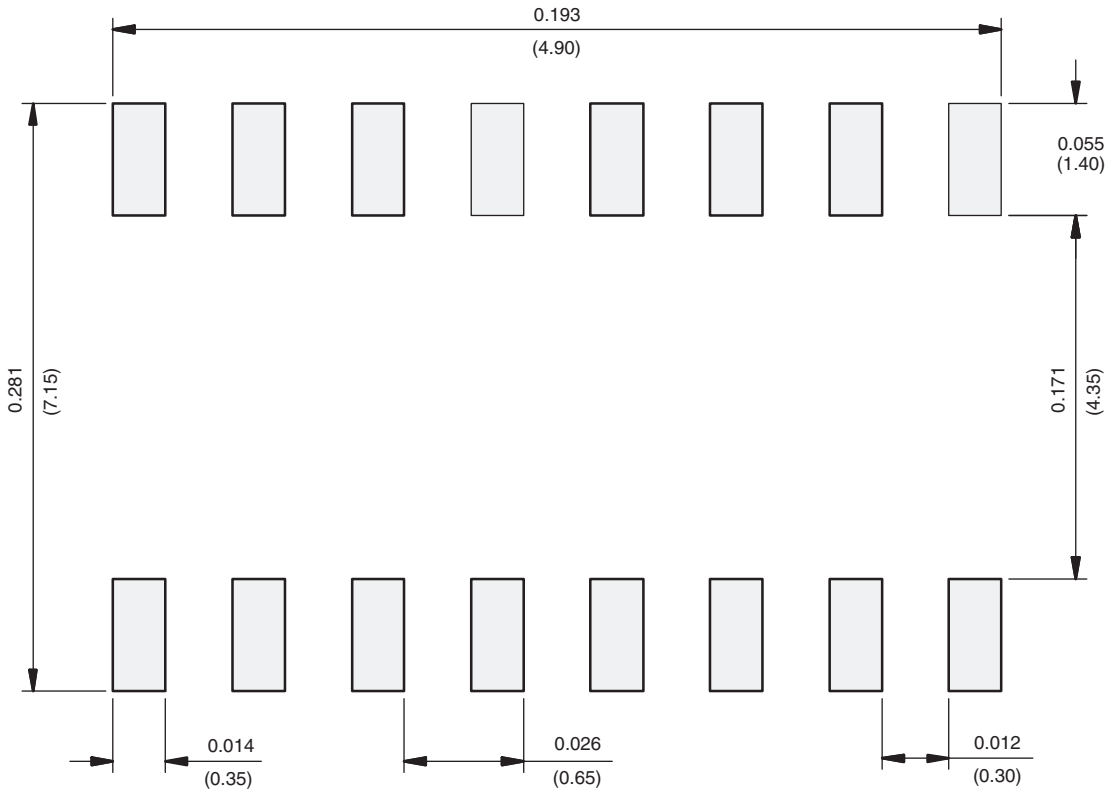






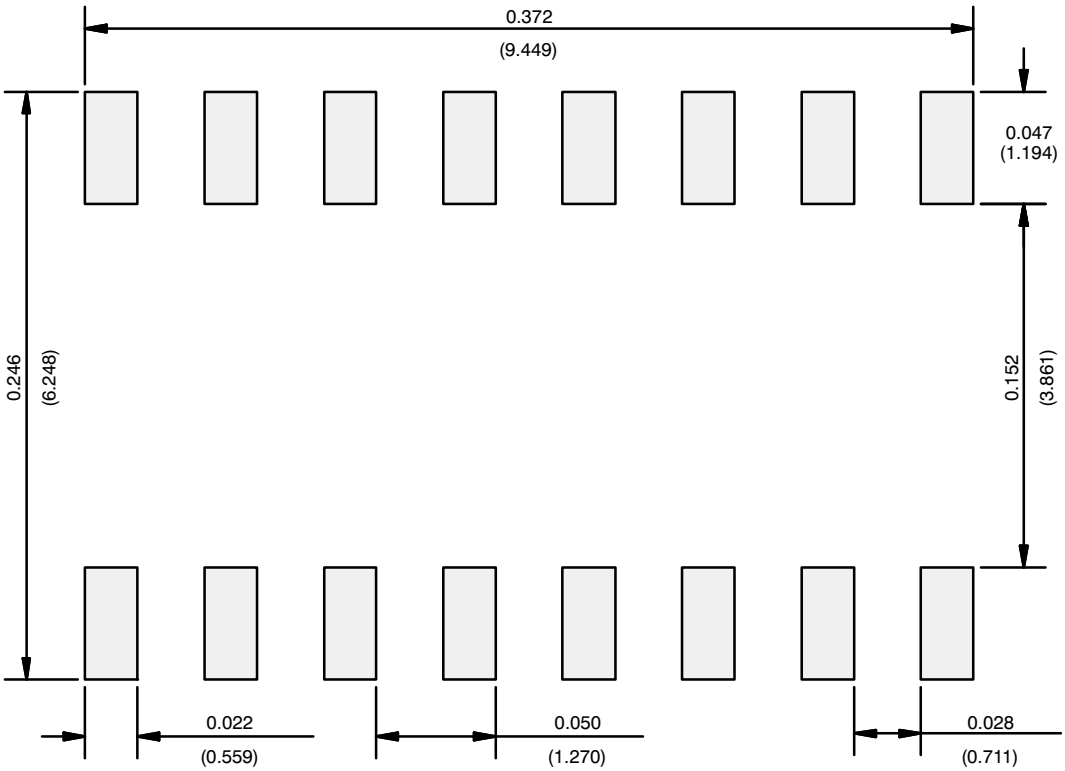
Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06 DWG: 5624			

RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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